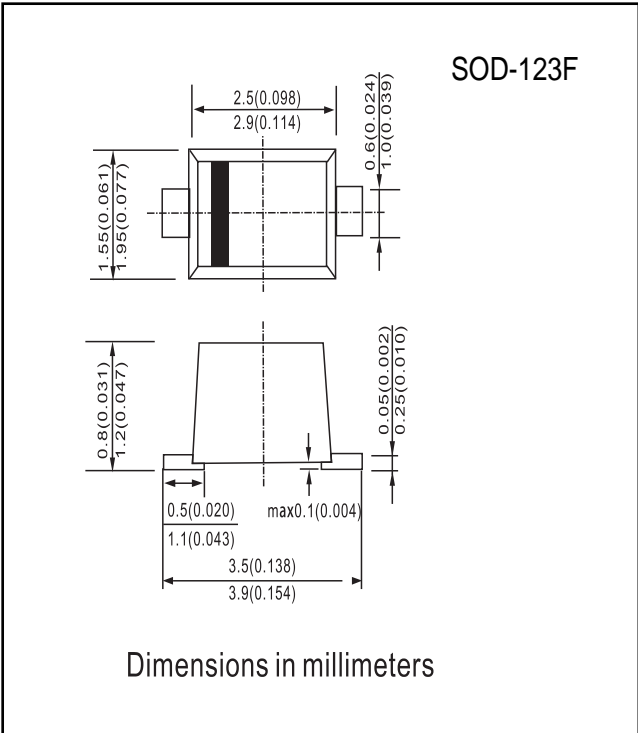




- FEATURES**
- Wide zener voltage range selection : 2.4V to 75V
VZTolerance Selection of $\pm 2\%$
 - Moisture sensitivity level 1
 - Matte Tin(Sn) lead finish with Nickel(Ni) underplate
 - Pb free version and RoHS compliant
 - Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

MECHANICAL DATA

- Case : Flat lead SOD-123 small outline plastic package
- Terminal: Matte tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- High temperature soldering guaranteed: 260
- Polarity : Indicated by cathode band
- Weight : 8.85 \pm 0.5 mg



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Maximum Ratings

Type Number	Symbol	Value	Units
Power Dissipation	P _D	500	mW
Forward Voltage	I _F =10mA V _F	1	V
Thermal Resistance (Junction to Ambient)	(Note 1) R θ JA	350	°C/W
Junction and Storage Temperature Range	T _J , T _{STG}	-65 to + 150	°C

Notes:1. Valid provided that electrodes are kept at ambient temperature



Electrical Characteristics

Ta = 25°C unless otherwise noted

Vf Forward Voltage = 1V Maximum @ If = 10 mA for all part numbers

Part Number	Vz @ IZT (Volt)			IZT(mA)	ZZT @ IZT(Ω) Max	Izk(mA)	Zzk @ Izk(Ω) Max	IR @ VR(μA) Max	VR(V)
	Nom	Min	Max						
BZT52B2V4	2.4	2.35	2.45	5	100	1	564	45	1
BZT52B2V7	2.7	2.65	2.75	5	100	1	564	18	1
BZT52B3V0	3	2.94	3.06	5	100	1	564	9	1
BZT52B3V3	3.3	3.23	3.37	5	95	1	564	4.5	1
BZT52B3V6	3.6	3.53	3.67	5	90	1	564	4.5	1
BZT52B3V9	3.9	3.82	3.98	5	90	1	564	2.7	1
BZT52B4V3	4.3	4.21	4.39	5	90	1	564	2.7	1
BZT52B4V7	4.7	4.61	4.79	5	80	1	470	2.7	2
BZT52B5V1	5.1	5	5.2	5	60	1	451	1.8	2
BZT52B5V6	5.6	5.49	5.71	5	40	1	376	0.9	2
BZT52B6V2	6.2	6.08	6.32	5	10	1	141	2.7	4
BZT52B6V8	6.8	6.66	6.94	5	15	1	75	1.8	4
BZT52B7V5	7.5	7.35	7.65	5	15	1	75	0.9	5
BZT52B8V2	8.2	8.04	8.36	5	15	1	75	0.63	5
BZT52B9V1	9.1	8.92	9.28	5	15	1	94	0.45	6
BZT52B10	10	9.8	10.2	5	20	1	141	0.18	7
BZT52B11	11	10.78	11.22	5	20	1	141	0.09	8
BZT52B12	12	11.76	12.24	5	25	1	141	0.09	8
BZT52B13	13	12.74	13.26	5	30	1	160	0.09	8
BZT52B15	15	14.7	15.3	5	30	1	188	0.045	10.5
BZT52B16	16	15.68	16.32	5	40	1	188	0.045	11.2
BZT52B18	18	17.64	18.36	5	45	1	212	0.045	12.6
BZT52B20	20	19.6	20.4	5	55	1	212	0.045	14
BZT52B22	22	21.56	22.44	5	55	1	235	0.045	15.4
BZT52B24	24	23.52	24.48	5	70	1	235	0.045	16.8
BZT52B27	27	26.46	27.54	2	80	0.5	282	0.045	18.9
BZT52B30	30	29.4	30.6	2	80	0.5	282	0.045	21
BZT52B33	33	32.34	33.66	2	80	0.5	306	0.045	23
BZT52B36	36	35.28	36.72	2	90	0.5	329	0.045	25.2
BZT52B39	39	38.22	39.78	2	130	0.5	329	0.045	27.3
BZT52B43	43	42.14	43.86	2	150	0.5	353	0.045	30.1
BZT52B47	47	46.06	47.94	2	170	0.5	353	0.045	33
BZT52B51	51	49.98	52.02	2	180	0.5	376	0.045	35.7
BZT52B56	56	54.88	57.12	2	200	0.5	400	0.045	39.2
BZT52B62	62	60.76	63.24	2	215	0.5	423	0.045	43.4
BZT52B68	68	66.64	69.36	2	240	0.5	447	0.045	47.6
BZT52B75	75	73.5	76.5	2	255	0.5	470	0.045	52.5

Notes:

1. The Zener Voltage (Vz) is tested under pulse condition of 10ms.
2. The device numbers listed have a standard tolerance on the nominal zener voltage of ±2%
3. For detailed information on price, availability and delivery of nominal zener voltages between the voltages shown and tighter voltage tolerances, contact your nearest **Taiwan semiconductor** representative.
4. The zener impedance is derived from the 60-cycle ac voltage, which results when an ac current having an rms value equal to 10% of the DC zener current (IZT or Izk) is superimposed to IZT or Izk.



RATINGS AND CHARACTERISTIC CURVES

BZT52B2V4 THRU BZT52B75

FIG 1 Typical Forward Characteristics

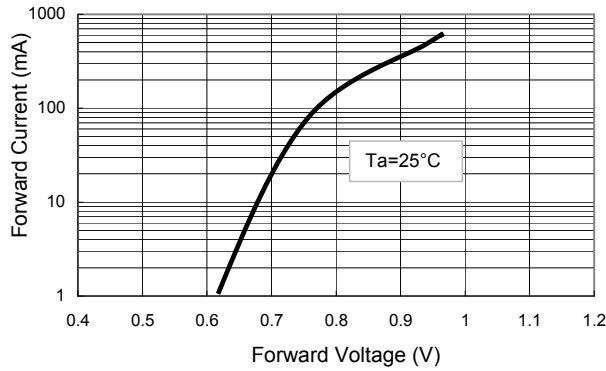


FIG 2 Zener Breakdown Characteristics

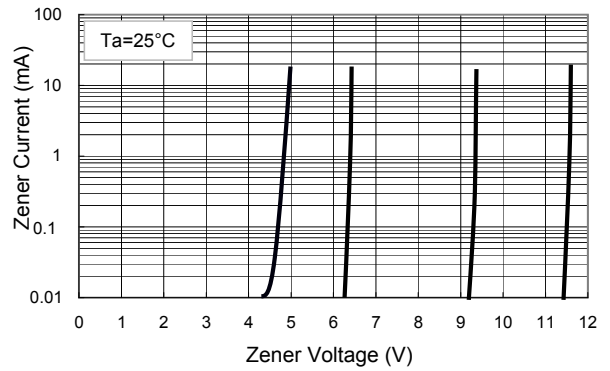


FIG 3 Zener Breakdown Characteristics

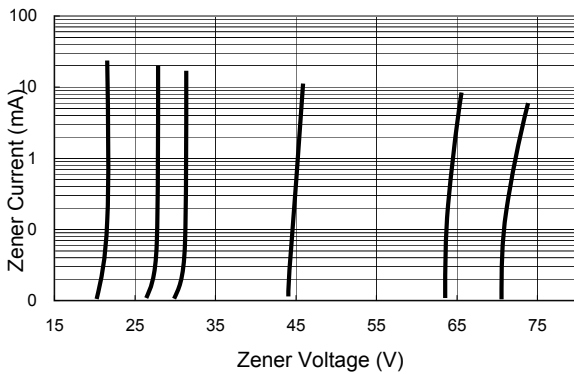


FIG 4 Admissible Power Dissipation Curve

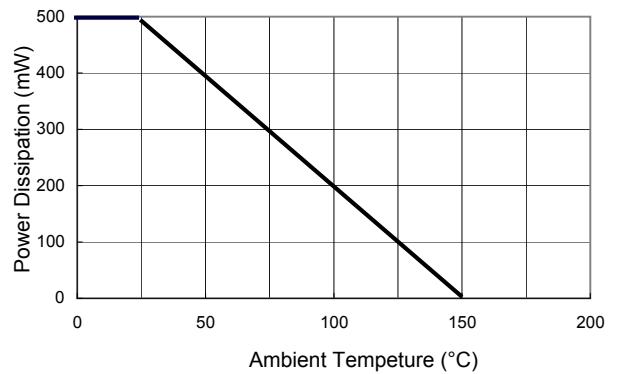


FIG 5 Typical Capacitance

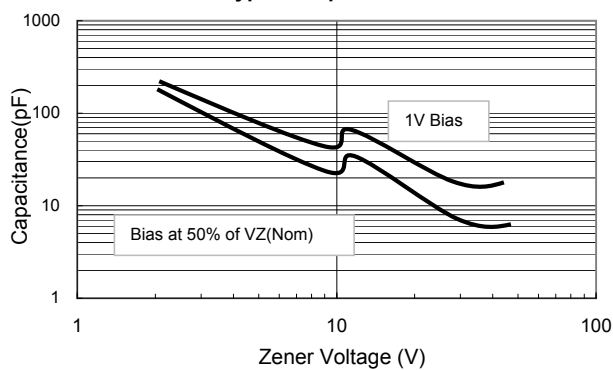


FIG 6 Effect of Zener Voltage on Impedance

